

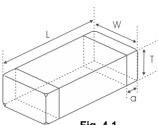
# KMOV0402E180C030T

#### 1. Electrical Characteristics

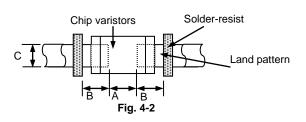
Please refer to Appendix A (Page 9~13).

- 1) Operating and storage temperature range (individual chip without packing): -55℃ ~ +125℃.
- 2) Storage temperature range (packaging conditions): -10  $^{\circ}C$  ~+40  $^{\circ}C$  RH 70% (Max.).

## 2. Shape and Dimensions

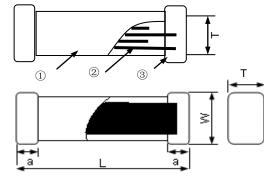


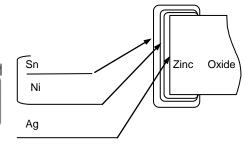




Unit: mm [inch]

Туре	L	W	Т	а	A	В	С
1005 [0402]	1.0±0.15 [0.039±0.006]	0.5±0.15 [0.020±0.006]	0.5±0.15 [0.020±0.006]	0.25±0.1 [0.010±0.004]	0.45~0.55	0.40~0.50	0.45~0.55





① ZnO for chip varistor

2 Internal electrode (Ag-Pd)

③-1 Terminal electrode: Inside (Ag)③-2 Outside (Electro-plating Ni-Sn)

Part Number	Max. Working Voltage		Varistor Voltage		Clamping Itage	Rated Sin Tran	•	Typical Capacitance
Test Condition	<2 DC	0µA AC RMS	@1mA DC	8/20µs	ESD	Energy 10/1000µs	Peak Current 8/20µs	@0.5V <sub>rms</sub> , 1MHz
Units	Volts	Volts	Volts	Volts	Volts	Joules	Amps	pF
Symbol	$V_{WDC}$	V <sub>WAC</sub>	V <sub>B</sub>	V <sub>C</sub> <sup>*1</sup>	V <sub>C</sub> <sup>*2</sup>	Eτ	l <sub>P</sub>	С
KMOV0402E180C030T	18.0	12.7	31.0-38.0	58	70	0.003	1	3

## 3. Test and Measurement Procedures

## 3.1 Test Conditions

3.1.1 Unless otherwise specified, the standard atmospheric conditions for measurement/test as:

- a. Ambient Temperature: 20±15°C.
- b. Relative Humidity: 65±20%.
- c. Air Pressure: 86kPa to 106kPa.
- 3.1.2 If any doubt on the results, measurements/tests should be made within the following limits:
  - a. Ambient Temperature: 20±2℃
  - b. Relative Humidity: 65±5%.
  - c. Air Pressure: 86kPa to 106kPa.

## 3.2 Visual Examination

a. Inspection Equipment:  $20 \times$  magnifier.

# 3.3 Electrical Test

Items	Requirements	Test Methods and Remarks		
3.3.1 Varistor Voltage at 1mA DC (V <sub>B</sub> )	Refer to Appendix A	Measuring current: 1mA DC Duration: 0.2 to 2 sec		
3.3.2 Capacitance (C)	Refer to Appendix A	Measure source: 0.5 V <sub>RMS</sub> Test frequency: 1MHz.		
3.3.3 Leakage Current (IL)	Refer to Appendix A	Measuring voltage: Maximum DC working voltage		
3.3.4 Clamping Voltage (V <sub>c</sub> )	Refer to Appendix A	Measuring source: 8/20us waveform, ESD waveform		

# 3.4 Reliability Test

Items	Requirements	Test Methods and Remarks
3.4.1. Terminal	No removal or split of the termination or other defects shall occur.	<ol> <li>Solder the chip to the testing jig (glass epoxy board shown in Fig.5.4.1-1) using eutectic solder. Then apply a force in the</li> </ol>
Strength	Chip Mounting Pad Glass Epoxy Board	<ul> <li>direction of the arrow.</li> <li>2 5N force for SDV1005 and 1608 series, 10N force for SDV2012 and 3216 series.</li> <li>3 Keep time: 10±1s.</li> </ul>
	Fig.5.4.1-1	

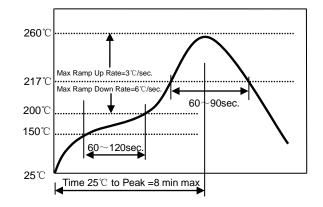
3.4.2 Resistance No visible mechanical damage.			① Solder the chip to the test jig (glass epoxy board shown in		
to Flexure	Type a	b c	Fig.3.4.2-1) using a eutectic solder. Then apply a force in the		
	1005[0402] 0.4	1.5 0.5	direction shown in <b>Fig.3.4.2-2</b> . ② Flexure: 2mm.		
	1608[0603] 1.0	3.0 1.2	<ol> <li>Pressurizing Speed: 0.5mm/sec.</li> </ol>		
			④ Keep time: 30 sec.		
	2012[0805] 1.2	4.0 1.65			
	3216[1206] 2.2	5.0 2.0			
	Fig.3.4		R230 45[1.772] Fig.5.4.2-2		
3.4.3 Vibration	No visible mechanical dam	Solder mask	<ol> <li>Solder the chip to the testing jig (glass epoxy board shown in Fig.3.4.3-1) using eutectic solder.</li> <li>The chip shall be subjected to a simple harmonic motion having total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55 Hz.</li> <li>The frequency range from 10 to 55 Hz and return to 10 Hz shall be traversed in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3mutually perpendicular directions (total of 6 hours).</li> </ol>		
3.4.4 Solderability	<ol> <li>No visible mechanical</li> <li>Wetting shall exceed state</li> </ol>	0	<ol> <li>Solder temperature: 240±2℃</li> <li>Duration: 3 sec.</li> <li>Solder: Sn/3.0Ag/0.5Cu.</li> <li>Flux: 25% Resin and 75% ethanol in weight.</li> </ol>		
3.4.5 Resistance to Soldering Heat			<ol> <li>Solder temperature: 260±3°C</li> <li>Duration: 5 sec.</li> <li>The chip shall be stabilized at normal condition for 1~2hours before measuring.</li> <li>Solder: Sn/3.0Ag/0.5Cu.</li> <li>Flux: 25% Resin and 75% ethanol in weight.</li> </ol>		
3.4.6 Thermal Shock	6 ① No visible mechanical damage. ①		<ol> <li>Transforming interval: 20sec. (max.)</li> <li>Tested cycle: 100 cycles.</li> </ol>		
	125℃ <sup>30</sup> min. Ambient Temperature ℃	30 min. 30 min. 20sec. (max.)	before measuring.		
3.4.7 Resistance to Low Temperature	<ol> <li>No visible mechanical</li> <li>Varistor voltage chanç</li> </ol>	-	<ol> <li>Temperature: -55±2℃</li> <li>Duration: 1000<sup>+24</sup> hours.</li> <li>The chip shall be stabilized at normal condition for 1~2 hours before measuring.</li> </ol>		
3.4.8 Resistance to High Temperature	<ol> <li>No visible mechanical</li> <li>Varistor voltage chang</li> </ol>	-	<ol> <li>Temperature: 125±2°C.</li> <li>Duration: 1000<sup>+24</sup> hours.</li> <li>The chip shall be stabilized at normal condition for 1~2 hours before measuring.</li> </ol>		
3.4.9 Damp Heat (Steady States)	<ol> <li>No visible mechanical</li> <li>Varistor voltage chang</li> </ol>	-	<ol> <li>Temperature: 60±2°C</li> <li>Humidity: 90% to 95% RH.</li> <li>Duration: 1000<sup>+24</sup> hours.</li> <li>The chip shall be stabilized at normal condition for 1~2 hours before measuring.</li> </ol>		

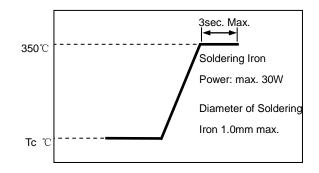
3.4.10 Loading Under Damp Heat 3.4.11	<ol> <li>No visible mechanical damage.</li> <li>Varistor voltage change: within ±10%.</li> <li>No visible mechanical damage.</li> </ol>	<ol> <li>Temperature: 60±2℃</li> <li>Humidity: 90% to 95% RH.</li> <li>Duration: 1000<sup>+24</sup> hours.</li> <li>Applied voltage: DC Working Voltage.</li> <li>The chip shall be stabilized at normal condition for 1~2 hours before measuring.</li> <li>Temperature: 125±2℃</li> </ol>
Loading at High Temperature (Life Test)	<ul> <li>Wo visible mechanical damage.</li> <li>Varistor voltage change: within ±10%.</li> </ul>	<ul> <li>Duration: 1000<sup>+24</sup> hours.</li> <li>Applied voltage: DC Working Voltage.</li> <li>The chip shall be stabilized at normal condition for 1~2 hours before measuring.</li> </ul>
3.4.12 Maximum Surge Current	<ol> <li>No visible mechanical damage.</li> <li>Varistor voltage change: within ±10%. IEC61000-4-5 standard 1.2/50us-8/20us voltage-current combination pulse</li> </ol>	<ol> <li>Temperature: 25±5℃</li> <li>Humidity: 30% to 65% RH.</li> <li>Number of hit: each 1 time of +/- polarity.</li> <li>Pulse waveform: 8/20 us.</li> <li>Applied current: maximum surge current (I<sub>P</sub>).</li> <li>The chip shall be stabilized at normal condition for 1~2 hours before measuring.</li> </ol>
3.4.13 Maximum Surge Energy	<ol> <li>No visible mechanical damage.</li> <li>Varistor voltage change: within ±10%. IEC61000-4-5 standard 10/1000us current pulse</li> </ol>	<ol> <li>Temperature :25±5℃</li> <li>Humidity: 30% to 65% RH.</li> <li>Number of hit: 1 time.</li> <li>Pulse waveform: 10/1000 us.</li> <li>Applied energy: maximum surge energy (E<sub>T</sub>).</li> <li>The chip shall be stabilized at normal condition for 1~2 hours before measuring.</li> </ol>
3.4.14 ESD Life	<ol> <li>No visible mechanical damage.</li> <li>Varistor voltage change: within ±10%. IEC61000-4-2 standard ESD gun C=150pF R=330Ω</li> </ol>	<ol> <li>Discharge: Contact discharge.</li> <li>Voltage: 8000V (Level 4).</li> <li>Polarity: +,</li> <li>Number: 10 times within 10 sec.</li> <li>The chip shall be stabilized at normal condition for 1~2 hours before measuring.</li> </ol>
3.4.15 ESD Test	<ol> <li>No visible mechanical damage.</li> <li>Varistor voltage change: within ±10%. IEC61000-4-2 standard ESD gun C=150pF R=330Ω</li> </ol>	<ol> <li>Discharge: Air discharge.</li> <li>Voltage: 15000V (Special level).</li> <li>Polarity: +, -</li> <li>Number: 10 times within 10 sec.</li> <li>The chip shall be stabilized at normal condition for 1~2 hours before measuring.</li> </ol>

#### 4. Recommended Soldering Technologies

- 4.1 Reflow Profile:
- $\triangle$  Preheat condition: 150 ~200°C/60~120sec.
- $\triangle$  Allowed time above 217C: 60~90sec.
- △ Max temp: 260°C
- $\triangle$  Max time at max temp: 10sec.
- △ Solder paste: Sn/3.0Ag/0.5Cu
- $\triangle$  Allowed Reflow time: 2x max

[Note: The reflow profile in the above table is only for qualification and is not meant to specify board assembly profiles. Actual board assembly profiles must be based on the customer's specific board design, solder paste and process, and should not exceed the parameters as the Reflow profile shows.]



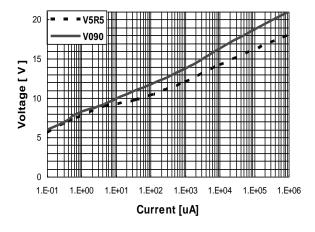


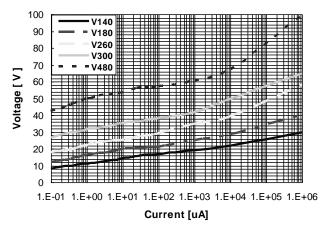
#### 4.2 Iron Soldering Profile.

- $\triangle$  Iron soldering power: Max.30W
- △ Pre-heating: 150 °C / 60 sec.
- $\triangle$  Soldering Tip temperature: 350 °C Max.
- $\triangle$  Soldering time: 3 sec Max.
- △ Solder paste: Sn/3.0Ag/0.5Cu
- △ Max.1 times for iron soldering

[Note: Take care not to apply the tip of the soldering iron to the terminal electrodes.]

# 5.characteristic curves of chip varistor





单击下面可查看定价,库存,交付和生命周期等信息

>>KUU(永裕泰)